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DISTRIBUTION STATEMENT A. Approved for public release; distribution is unlimited.

1. SCOPE 1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1. $\overline{2.1}$ of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices". 1.2 Part number. The complete part number shall be as shown in the following example: 5962-87646 Lead finish per Drawing number Device type Case outline MIL-M-38510 (1.2.1)(1.2.2)1.2.1 Device type. The device type shall identify the circuit function as follows: Device type Generic number Circuit function 01 14490A Hex contact bounce eliminator 1.2.2 Case outline. The case outline shall be as designated in appendix C of MIL-M-38510, and as follows: Outline letter .Case outline D-2 (16-lead, 1/4" x 7/8"), dual-in-line package Ε 1.3 Absolute maximum ratings. -0.5 V dc to +18 V dc -0.5 to V_{DD} +0.5 V dc ±10 mA -65°C to +150°C Maximum power dissipation (P_D) 1/------Lead temperature (soldering, 8 seconds)-----500 mW +260°C Thermal_resistance, junction-to-case (θ_{JC}): Case E - - - - -(See MIL-M-38510, appendix C) +175°C 1.4 Recommended operating conditions. Supply voltage - - - -+5 Y dc to +15 Y dc Case operating temperature range (T_C)- -- -- Oscillator frequency (OSC_{OUT}) at +25 °C with -55°C to +125°C CEXT > 100 pF: $1.5/C_{EXT}$ (in $\mu F)$ Hz $4.5/C_{EXT}$ (in $\mu F)$ Hz $6.5/C_{EXT}$ (in $\mu F)$ Hz 1/ For $T_C = +100$ to +125°C, derate linearly at 12 mW/°C to 200 mW. SIZE STANDARDIZED 5962-87646 Α

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宣问"5962-8764601EA"供应商 2. APPLICABLE DOCUMENTS

2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510

- Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883

Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

- 2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.
 - 3. REQUIREMENTS
- 3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 <u>Design</u>, construction, and physical <u>dimensions</u>. The design, construction, and physical <u>dimensions</u> shall be as specified in MIL-M-38510 and herein.
 - 3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.2 Block diagram. The block diagram shall be as specified on figure 2.
 - 3.2.3 Case outline. The case outline shall be in accordance with 1.2.2 herein.
- 3.3 Electrical performance characteristics. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full recommended case operating temperature range.
- 3.4 <u>Marking</u>. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.
- 3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.
- 3.6 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.

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Test	Symbol	C	onditions T _C < +125°C	Group A subgroups	Lim	l Unit I	
	<u> </u>	unless ō	therwise specified		Min	Max 	
High-level output voltage	I V _{OH}	V _{DD} = 5.0 V V _{DD} = 10 V dc V _{DD} = 15 V dc	$V_{IN} = V_{DD} \text{ or } 0$ $ I_0 < 1 \mu A$	1, 2, 3	4.95 9.95 14.95		V
Low-level output voltage	 v _{OL} 	V _{DD} = 5.0 V dc V _{DD} = 10 V dc V _{DD} = 15 V dc	$V_{IN} = V_{DD}$ or 0 $i I_0 i < 1 \mu A$	1, 2, 3		.05 .05 .05	 V
High-level input voltage	IV _{IH}	V _{DD} = 5.0 V dc V _O = 0.5 V dc o	r 4.5 V dc	1, 2, 3	3.5		V
		$V_{DD} = 10 \text{ V dc},$	V ₀ = 1.0 V dc or 9.0	V dc	7.0		
		V _{DD} = 15 V dc	V ₀ = 1.5 V dc or 13.5 V d	c	11.0]
Low-level input voltage	VIL	V _{DD} = 5.0 V dc V ₀ = 0.5 V dc o	r 4.5 V dc	1, 2, 3		1.5	V
		V _{DD} = 10 V dc,	V ₀ = 1.0 V dc or 9.0	V dc		3.0]
		V _{DD} = 15 V dc	V ₀ = 1.5 V dc or 13.5 V d I ₀ < 1 μA	lc		4.0]
High-level current, oscillator output	1 _{ОН1}	V _{DD} = 5 V dc V _O = 4.6 V dc V _{IN} = 0 or 5 V	$T_{C} = -55^{\circ}C$ $T_{C} = +25^{\circ}C$ $T_{C} = +125^{\circ}C$	1, 2, 3	-0.12 -0.1 -0.08		l mA
		V _{DD} = 10 V dc V ₀ = 9.5 V dc V _{IN} = 0 or 10 V	$T_{C} = -55^{\circ}C$ $T_{C} = +25^{\circ}C$ $T_{C} = +125^{\circ}C$		-0.23 -0.20 -0.16		
		V _{DD} = 15 V dc V _O = 13.5 V dc V _{IN} = 0 or 15 V	$T_{C} = -55^{\circ}C$ $T_{C} = +25^{\circ}C$ $T_{C} = +125^{\circ}C$		-1.4 -1.2 -1.0		
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Test	Symbol	C	onditions T _{C <} +125°C	Group A		Unit	
		-55 C < unless o	subgroups 	Min	Max	 	
figh-level current, debounce outputs	^I 0H2	V _{DD} = 5 V dc V _O = 4.6 V dc V _{IN} = 0 or 5 V	$T_{C} = -55^{\circ}C$ $T_{C} = +25^{\circ}C$ dc $T_{C} = +125^{\circ}C$	1, 2, 3	-0.19 -0.16 -0.12		mA
		V _{DD} = 10 V dc V _O = 9.5 V dc V _{IN} = 0 or 10 V	T _C = -55°C T _C = +25°C dc T _C = +125°C		-0.60 -0.50 -0.40		
		$ V_{DD} = 15 \text{ V dc}$ $ V_{OD} = 13.5 \text{ V dc}$ $ V_{IN} = 0 \text{ or } 15 \text{ V}$	$T_{C} = -55^{\circ}C$ $T_{C} = +25^{\circ}C$ dc $T_{C} = +125^{\circ}C$		-1.8 -1.5 -1.2		
Low-level current, oscillator output	I _{OL1}	V _{DD} = 5 V dc V _O = 0.4 V dc V _{IN} = 0 or 5 V	$T_{C} = -55^{\circ}C$ $T_{C} = +25^{\circ}C$ dc $T_{C} = +125^{\circ}C$	1, 2, 3	0.36 0.30 0.24		mA
	1	$ V_{DD} = 10 \text{ V dc}$ $ V_{O} = 0.5 \text{ V dc}$ $ V_{TN} = 0 \text{ or } 10 \text{ V}$	$T_{C} = -55^{\circ}C$ $T_{C} = +25^{\circ}C$ $T_{C} = +125^{\circ}C$		0.9 0.75 0.6		-
		$ V_{DD} = 15 \text{ V dc}$ $ V_{O} = 1.5 \text{ V dc}$ $ V_{IN} = 0 \text{ or } 15 \text{ V}$	$T_{C} = -55^{\circ}C$ $T_{C} = +25^{\circ}C$ $T_{C} = +125^{\circ}C$		4.2 3.5 2.8		
Low-level current, debounce outputs		V _{DD} = 5 V dc V _O = 0.4 V dc V _{IN} = 0 or 5 V	$T_{C} = -55^{\circ}C$ $T_{C} = +25^{\circ}C$ dc $T_{C} = +125^{\circ}C$	1, 2, 3	2.6 2.2 1.8		inA
		$V_{DD} = 10 \text{ V dc}$ $V_{O} = 0.5 \text{ V dc}$ $V_{IN} = 0 \text{ or } 10 \text{ V}$	$T_{C} = -55^{\circ}C$ $T_{C} = +25^{\circ}C$ $T_{C} = +125^{\circ}C$		4.0 3.3 2.7		
		$V_{DD} = 15 \text{ V dc}$ $V_{0} = 1.5 \text{ V dc}$ $V_{1N} = 0 \text{ or } 15 \text{ V}$	$T_{C} = -55^{\circ}C$ $T_{C} = +25^{\circ}C$ $T_{C} = +125^{\circ}C$		12 10 6.4	 	
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Test	Symbol	! 	ditions C < +125°C	 Group A subgroups		imits	Uni
		i unless ōth i	erwise specified		Min	i Max	
Input current, debounce inputs	IIH	! V _{IN} = V _{DD} V _{DD} = 15 V	T _C = -55°C T _C = +25°C	1, 3	} 	2.0	 μ Α
	i i	 	$T_C = +125^{\circ}C$	2	 	11.0	†
Input current, debounce inputs	IIL	 V _{IN} = V _{SS} V _{DD} = 5 V	T _C = -55°C T _C = +25°C T _C = +125°C	1, 2, 3	210 140 70	450 280 160	μА
		V _{IN} = V _{SS} V _{DD} = 10 V	T _C = -55°C T _C = +25°C T _C = +125°C		415 280 145	900 560 320	 - -
		 V _{IN} = V _{SS} V _{DD} = 15 V 	T _C = -55°C T _C = +25°C T _C = +125°C		610 415 215	1350 840 480	
input current, oscillator	I IIN	 V _{IN} = 0 or 15 V de 	c, T _C = -55°C T _C = +25°C T _C = +125°C	1, 2, 3		±620 ±400 ±250	μΑ
Quiescent current	i I _{DD} i i	 Y _{DD} = 5 V dc Y _{IN} = 0 V or V _{DD} I _O = 0 µA	T _C = -55°C T _C = +25°C T _C = +125°C	1, 2, 3		150 100 90	μА
		V _{DD} = 10 V dc V _{IN} = 0 V or V _{DD} I _O = 0 μA	T _C = -55°C T _C = +25°C T _C = +125°C			280 225 180	
		V _{DD} = 15 V dc V _{IN} = 0 V or V _{DD} I _O = 0 μA	T _C = -55°C T _C = +25°C T _C = +125°C			840 650 550	
nput capacitance	CIN	V _{IN} = 0 V dc See 4.3.1c	T _C = +25°C	4		7.5	pF
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TABLE I. Electrical performance characteristics - Continued. Test |Symbol Conditions $-55^{\circ}\text{C} < \text{T}_{\text{C}} < +125^{\circ}\text{C}$ unless otherwise specified Unit Group A Limits subgroups Min Max |T_C = +25°C |C_L = 50 pF ±10% Propagation delay | t_{PHL} 9 570 $V_{DD} = 5 V$ ns time, high-to-low level, oscillator V_{DD} = 10 V V_{DD} = 15 V 240 190 input to debounce outputs T_C = -55°C, +125°C $\begin{array}{l}
 V_{DD} &=& 5 \quad V \\
 V_{DD} &=& 10 \quad V \\
 V_{DD} &=& 15 \quad V
 \end{array}$ 10, 11 1/ 360 $C_1 = 50 \text{ pF } \pm 10\%$ 285 T_C = +25°C |C_L = 50 pF ±10% $\begin{array}{ccccc} v_{DD} &=& 5 & v \\ v_{DD} &=& 10 & v \\ v_{DD} &=& 15 & v \end{array}$ |t_{PLH} 9 740 Propagation delay กร time, low-to-high! 320 level, oscillator input to debounce 240 outputs $V_{DD} = 5 V \\ V_{DD} = 10 V \\ V_{DD} = 15 V$ T_C = -55°C, +125°C 10, 11 1110 480 1/ 360 $|C_L = 50 pF \pm 10\%$ $\begin{array}{ccccc} v_{DD} &=& 5 & v \\ v_{DD} &=& 10 & v \\ v_{DD} &=& 15 & v \end{array}$ T_C = +25°C C_L = 50 pF ±10% Output rise time, 9 360 ns | t_{TLH} 180 all outputs 130 $\begin{array}{l} v_{DD} = 5 \text{ V} \\ v_{DD} = 10 \text{ V} \\ v_{DD} = 15 \text{ V} \end{array}$ T_C = -55°C, +125°C 10, 11 540 1/ 270 195 $|C_{L} = 50 \text{ pF } \pm 10\%$ T_C = +25°C |C_L = 50 pF ±10% $\begin{array}{ccccc} \mathbf{Y}_{DD} &=& 5 & \mathbf{V} \\ \mathbf{Y}_{DD} &=& 10 & \mathbf{V} \\ \mathbf{V}_{DD} &=& 15 & \mathbf{V} \end{array}$ 200 Output fall time, 9 ns !tTHL1 oscillator output 100 80 1/ $T_{C} = -55^{\circ}C$, +125°C $V_{DD} = 5 V$ $V_{DD} = 10 V$ 10, 11 300 150 $C_L = 50 \text{ pF } \pm 10\%$ $V_{DD}^{DD} = 15 \text{ V}$ 120 T_C = +25°C |C_L = 50 pF ±10% $V_{DD} = 5 V$ Output fall time, tTHL2 9 120 ns V_{DD} = 10 V V_{DD} = 15 V debounce outputs 60 40 1/ T_C = -55°C, 1 +125°C $V_{DD} = 5 V$ $V_{DD} = 10 V$ 10, 11 180 90 $|C_L = 50 \text{ pF } \pm 10\%$ $V_{DD} = 15 \text{ V}$ 60 See footnote at end of table. SIZE **STANDARDIZED** 5962-87646 Α **MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER REVISION LEVEL** SHEET 7 DAYTON, OHIO 45444

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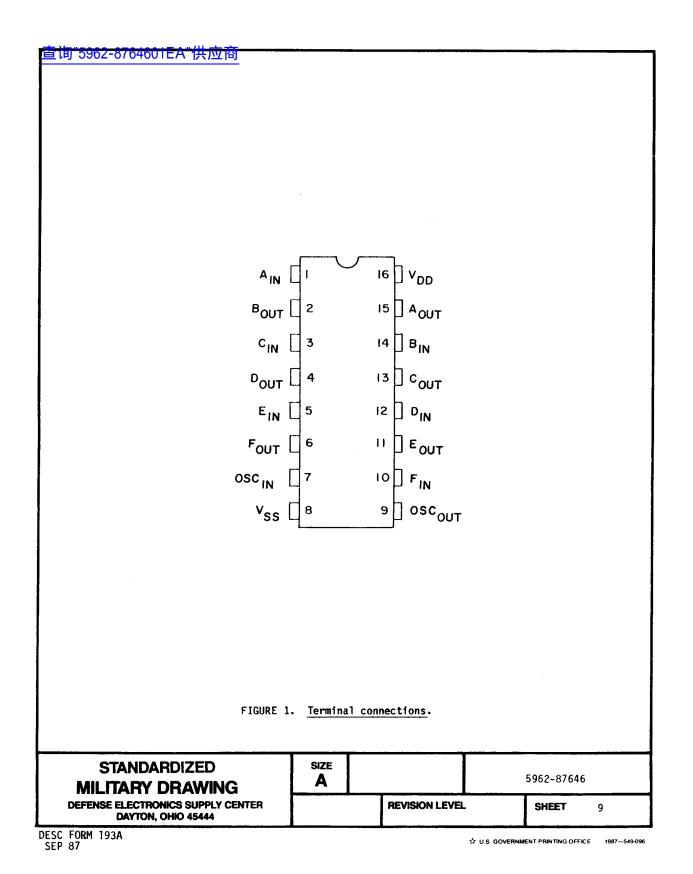
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Test Symbo Setup time $\underline{1}/$ t_{SU}	 Symbol	i Condi	tions	Group A	Li	l Unit	
		-55°C < T _C unless other	c +125°C wise specified	subgroups 	Min	Max)
	tsu	T _C = +25°C C _L = 50 pF ±10%	V _{DD} = 5 V V _{DD} = 10 V V _{DD} = 15 V	9	155 80 60		ns
		T _C = -55°C, +125°C C _L = 50 pF ±10%	V _{DD} = 5 V V _{DD} = 10 V V _{DD} = 15 V	10, 11	233 120 90		
Clock frequency (external clock) (50% duty cycle)	f _{CL}	T _C = +25°C C _L = 50 pF ±10%	V _{DD} = 5 V V _{DD} = 10 V V _{DD} = 15 V	9		1.4 3.0 4.5	i MHz
<u>1</u> /	 	T _C = -55°C, +125°C C _L = 50 pF ±10%	V _{DD} = 5 V V _{DD} = 10 V V _{DD} = 15 V	10, 11		1.4 3.0 4.5	

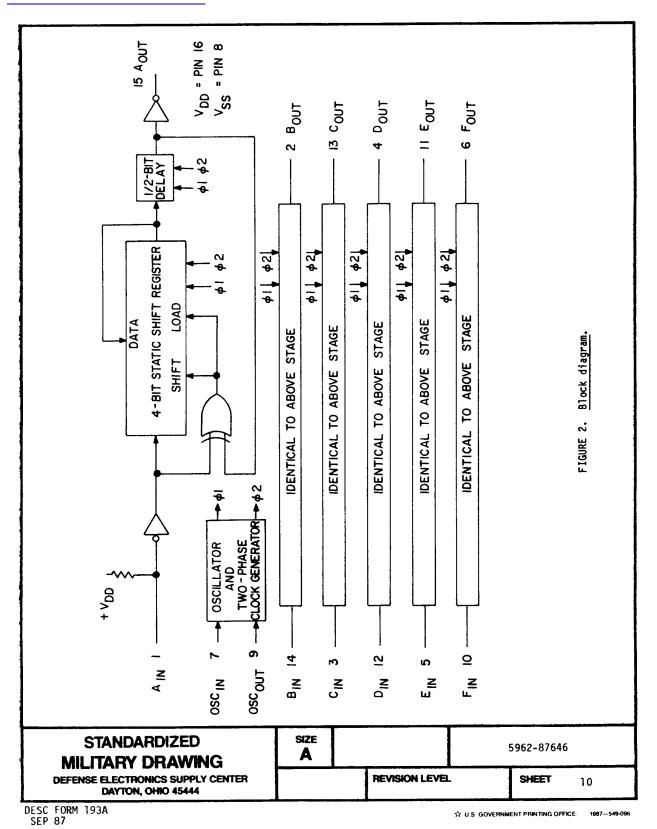
- 1/ AC limits at V_{DD} = 10 V and V_{DD} = 15 V shall be guaranteed if not tested. See figure 3.
- 3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).
- 3.8 <u>Verification and review.</u> DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
 - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test (method 1015 of MIL-STD-883).
 - (1) Test condition A or D using the circuit submitted with the certificate of compliance (see $3.5\ \text{herein}$).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

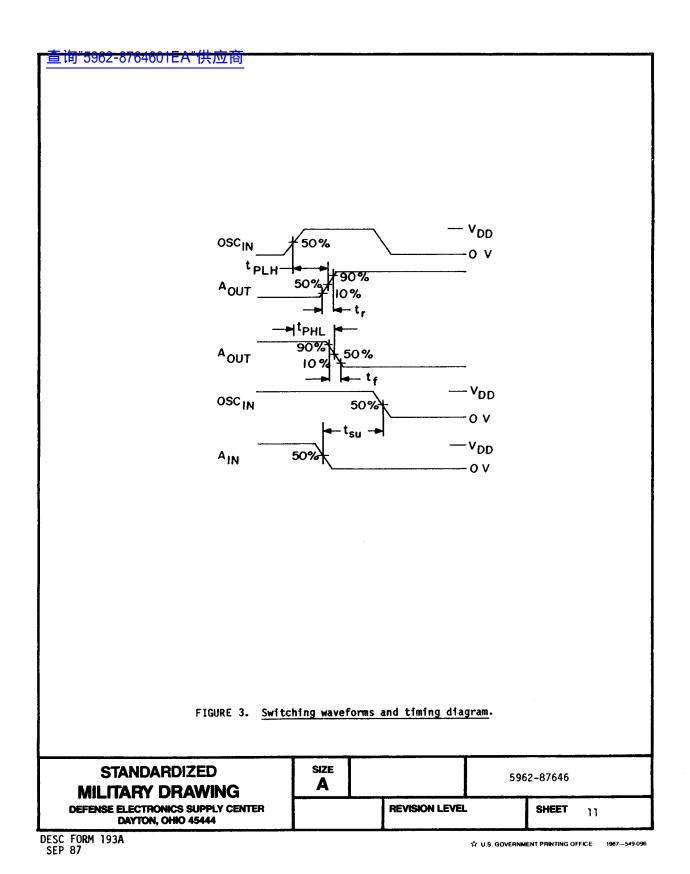
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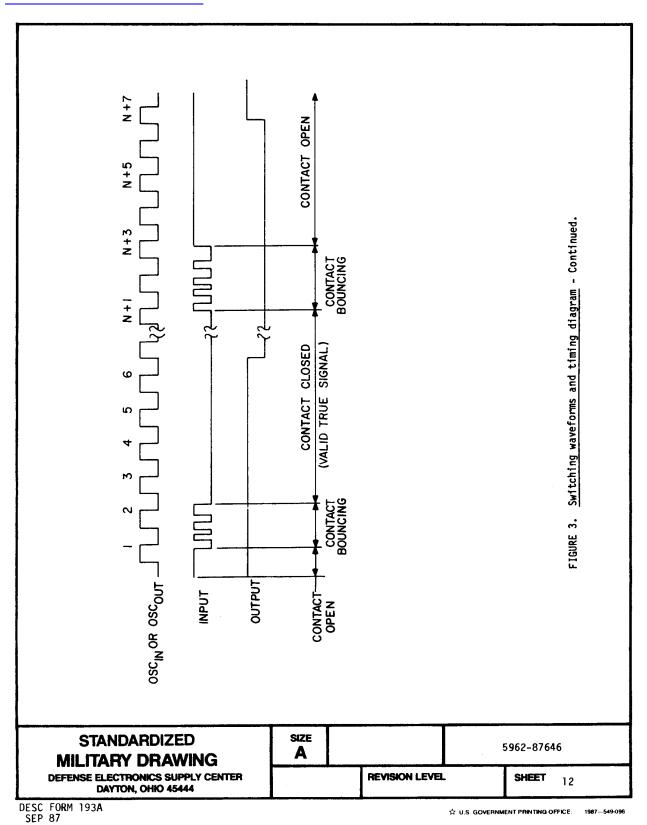


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MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004)	
Final electrical test parameters (method 5004)	1*, 2, 3, 9
Group A test requirements (method 5005)	1, 2, 3, 4, 9, 1 10, 11**
 Groups C and D end-point electrical parameters (method 5005)	1, 2, 3

* PDA applies to subgroup 1.

- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-SID-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
 - 4.3.1 Group A inspection.
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 5, 6, 7, and 8 in table I, method 5005 of MIL-STD-883 shall be omitted.
 - c. Subgroup 4 ($C_{\hbox{\scriptsize IN}}$ measurement) shall be measured only for the initial test and after process or design changes which may affect input capacitance.
 - 4.3.2 Groups C and D inspections.
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. Steady-state life test (method 1005 of MIL-STD-883) conditions:
 - (1) Test condition A or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125$ °C, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by appendix B of MIL-M-38510 and method 1005 of MIL-STD-883.

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^{**} Subgroups 10 and 11, if not tested, shall be guaranteed to the specified limits in table I.

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- 5. PACKAGING
- 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.
 - 6. NOTES
- 6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
- 6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.
- 6.4 Approved sources of supply. Approved sources of supply are listed herein. Additional sources will be added as they become available. The vendors listed herein have agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

Military drawing part number	Vendor CAGE number	Vendor similar part number <u>1</u> /	Replacement military specification part number
5962-8764601EX	04713	14490A/BEAJC	

 $\frac{1}{-}$ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE number

04713

Vendor name and address

Motorola, Incorporated 7402 S. Price Road Tempe, AZ 85283

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